

# M635

DIELECTRIC RESONATOR VCO

### **GENERAL DESCRIPTION**

The M635 Voltage Controlled Dielectric Resonator Oscillator (VCDRO) is specifically designed for high-speed SONET/SDH OC-192 applications and beyond. With an available center frequency range of 10 to 14GHz, and a tuning range of up to 40MHz, the VCDRO can be used in both OC-192 and OC-768 applications. The tuning range is  $\pm$ 1000 ppm from center frequency.

The integrated Dielectric Resonator provides this VCO with low phase noise performance and excellent tuning linearity. The linear tuning range makes the M635 especially suited for phase-locked loop implementations, clock and data recovery circuits, and other timing applications for the telecom and optical fiber networking markets (OC-192/STM-64 with and without Forward Error Correction - FEC).

### **FEATURES**

- Voltage Controlled DRO center frequencies from 10 to 14 GHz (Specify center frequency at time of order)
- ◆ Low phase jitter 0.05ps rms typical (50kHz to 80MHz)
- ◆ Low phase noise -65dBc/Hz @ 1kHz offset
- ◆ Very linear and broad tuning range of 10 to 40MHz
- ◆ Ideal for high-speed fiber optic applications
- Single 5V power supply

**BLOCK DIAGRAM** 

Small 1.25 x 1.5 inch SMA connector package

### **PIN ASSIGNMENT (1.25 x 1.5 inch SMA)**



Figure 1: Pin Assignment

#### Sample of Available Output Frequencies

VCDRO Center Frequency <sup>1</sup> (GHz)	Applications
10 GHz	OC-192
10.664 GHz	OC-192, OTU2 FEC
14 GHz	OC-192

Table 1: Sample of Available Output Frequencies

Note 1: Specify VCDRO center frequency at time of order



Figure 2: Block Diagram



### **PIN DESCRIPTIONS**

Name	I/O	Description
GND	Ground	Power supply ground connections.
VCC	Power	Power supply connection, connect to +5.0V.
VIN	Input	Tuning Voltage
RF_OUT	Output	Clock output. SMA connector.

Table 2: Pin Descriptions

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Symbol	Parameter	Rating	Unit
V <sub>cc</sub>	Power Supply Voltage	5.25	V
Τ <sub>s</sub>	Storage Temperature	-40 to +125	°C
u		Table 3: Absolute Maxir	num Ratings

Note 1:Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings and stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in Recommended Conditions of Operation, DC Characteristics, or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

### **RECOMMENDED CONDITIONS OF OPERATION**

	Symbol	Parameter	Min	Тур	Max	Unit
	$V_{cc}$	Positive Supply Voltage	4.75	5.0	5.25	V
Ī	T <sub>A</sub>	Ambient Operating Temperature	-40		+85	°C

Table 4: Recommended Conditions of Operation

### **ELECTRICAL SPECIFICATIONS**

#### **DC Characteristics**

Unless stated otherwise,  $V_{CC} = 5.0$  Volts  $\pm 5\%$ ,  $T_A = 25$  °C, VCDRO Frequency =10-14GHz, Outputs terminated into  $50\Omega$ 

	Symbol	Parameter	Min	Тур	Max	Unit
Power Supply	y V <sub>cc</sub>	Positive Supply Voltage	4.75	5.0	5.25	V
	I <sub>cc</sub>	Power Supply Current			150	mA
Tuning		Tuning Port Impedence	2			kΩ
	V <sub>IN</sub>	Tuning Voltage	0		15	V

Table 5: DC Characteristics



### **ELECTRICAL SPECIFICATIONS (CONTINUED)**

#### **AC Characteristics**

Unless stated otherwise,  $V_{CC} = 5.0$  Volts  $\pm 5\%$ ,  $T_A = 25$  °C, VCDRO Frequency =10-14GHz, Outputs terminated into 50 $\Omega$ 

Symbol	Parameter		Min	Тур	Max	Unit
F <sub>OUT</sub>	Output Center Frequency Range		10		14	GHz
	Temperature Stability			±300		ppm
	Output Power		6			dBm
	Tuning Range		10	20	40	MHz
	Tuning Linearity			10		%
	VCO Gain KVCO			200		ppm/V
APR	Absolute Pull-Range		±1000			ppm
	Non-harmonic Spurious				-60	dBc
	Harmonics				-25	dBc
Φn	Single Side Band	1kHz Offset		-65		dBc/Hz
	Phase Noise	10kHz Offset		-90		dBc/Hz
		100kHz Offset		-110		dBc/Hz
J(t)	Jitter (rms)	50kHz to 80MHz		0.05		ps
	Load VSWR (Voltage Sta	anding Wave Ratio)		1.5:1		

Table 6: AC Characteristics

## TEST DATA

**Phase Noise:** 



Figure 3: Phase Noise

#### **Frequency Tuning Characteristics**

Frequency Offset (ppm) vs. Tuning Voltage (V)



Figure 4: Frequency Tuning Characteristics



### **TEST DATA (CONTINUED)**

#### **Typical Temperature Characteristics**

Frequency Shift (ppm) vs. Temperature (<sup>o</sup>C)





Output Power Change vs. Temperature (°C)

Figure 6: Output Power Change vs. Temperature (oC)

### DEVICE PACKAGE - 1.25 x 1.5 inch CONNECTOR MODULE

### **Mechanical Dimensions:**



Figure 7: Device Package - 1.25 x 1.5 inch Connector Module

### **ORDERING INFORMATION**

For VCDRO Frequency (GHz)	Order Part Number
10.664	M635-10.6640
	Table 7: Ordering Information
Consult ICS for the availability of c	other VCDRO frequencies.

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